## NSN 5961-01-333-1455

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-333-1455 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.086 inches and 0.106 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 9.6 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 milliamperes forward current, average absolute **Capacitance Rating In Picofarads:** 130.0 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0